

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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12-11-02
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In re the Application of: **KANO, Takashi et al.**

Group Art Unit: 2812

Serial No.: **09/941,982**

Examiner: **MULPURI, Savitri**

Filed: **August 30, 2001**

P.T.O. Confirmation No.: 7536

For. **METHOD OF FORMING NITRIDE-BASED SEMICONDUCTOR LAYER, AND
METHOD OF MANUFACTURING NITRIDE-BASED SEMICONDUCTOR
DEVICE**

PETITION FOR EXTENSION OF TIME

Commissioner for Patents
Washington, D.C. 20231

Date: November 27, 2002

Sir:

Applicants petition the Commissioner for Patents to extend the time for response to the Office Action dated June 28, 2002 for two months from September 28, 2002 to November 28, 2002.

Attached please find a check in the amount of \$400.00 to cover the cost of the extension for a large entity. In the event that any additional fees are due in connection with this paper, please charge our Deposit Account No. 01-2340. Two copies of this paper are enclosed herewith.

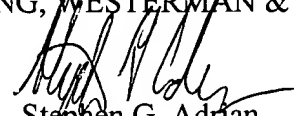
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400.00 OP

Respectfully submitted,

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